TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA48M025F,TA48M03F,TA48M033F, TA48M0345F,TA48M04F,TA48M05F

2.5 V, 3 V, 3.3 V, 3.45 V, 4 V, 5 V

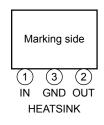
Three-Terminal Low Dropout Voltage Regulator

The TA48M**F series consists of fixed-positive-output, low dropout regulators with an output current of 500 mA (max). In response to the need for low voltage devices, the series offers devices with low output voltages of 2.5 V, 3 V, 3.3 V, 3.45 V, and 4 V, which are not included in the existing TA78DM**S series (0.5 A low dropout).

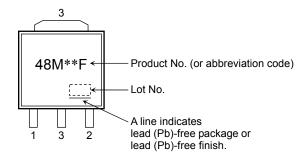
Features

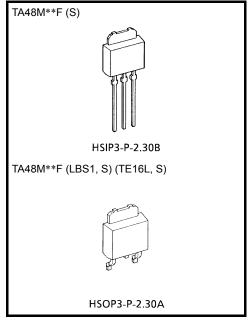
- Maximum output current of 0.5 A
- Low standby current: 0.8 mA (typ.)
- Low dropout voltage: 0.65 V (max) @IOUT = 0.5 A
- Protection function: overheat/overcurrent/overvoltage/reversed power supply connections.
- PW-Mold package: Surface-mount type for reflow soldering is also supported.

Pin Assignment



Marking





Weight

HSIP3-P-2.30B: 0.36 g (typ.) HSOP3-P-2.30A: 0.36 g (typ.)

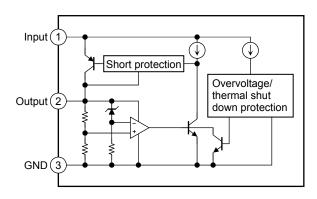


Ordering Method (Note 1)

	Product Name	Package (Lead Type)	Packing Form				
1	TA48M**F (S)	PW-Mold: Straight lead	Sack (200 pcs./sack)				
2	TA48M**F (LBS1, S)	PW-Mold: Surface-mount	Stick (100 pcs. max)				
	TA48M**F (TE16L, S)	PW-Mold: Surface-mount	Tape (700 pcs./reel)				

Note 1: The "**" in each pro-forma product name is replaced with the output voltage of each product. For example: for 3 V, "TA48M03F"

Block Diagram



Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit
Input voltage		V _{IN}	29	V
Output current	Output current		0.5	А
Power dissipation	(Ta = 25°C)	PD	1	W
Fower dissipation	(Tc = 25°C)	۲۵	10	VV
Operating temperature	!	T _{opr}	-40 to 85	°C
Storage temperature		T _{stg}	-55 to 150	°C
Junction temperature		Tj	150	°C
Thermal resistance		R _{th (j-c)}	12.5	°C/W
Thermal resistance		R _{th (j-a)}	125	C/VV

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

2

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Protection Function

Characteristics	Symbol	Min	Тур.	Max	Unit
Overvoltage	V _{IN}	29	33	_	V
Overheat	Tj	_	175	_	°C



TA48M025F

Electrical Characteristics (unless otherwise specified, $V_{IN}=4.5$ V, $I_{OUT}=250$ mA, $T_j=25$ °C, $C_{IN}=0.1$ μF , $C_{OUT}=10$ μF)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	2.4	2.5	2.6	
Output voltage	Vout	_	$\begin{array}{l} 3.5 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ 5 \text{ mA} \leq \text{I}_{OUT} \leq 500 \text{ mA}, \\ 0^{\circ}\text{C} \leq \text{T}_{j} \leq 125^{\circ}\text{C} \end{array}$	2.375	2.5	2.625	V
Line regulation	Reg·line	_	$3.5~V \leq V_{IN} \leq 16~V$	_	7	18	mV
Load regulation	Reg·load	_	5 mA ≤ I _{OUT} ≤ 500 mA	_	45	90	mV
Quiescent current	IB	_	$3.5 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ \text{I}_{OUT} = 0 \text{ mA}$	_	0.8	1.4	- mA
Quiescent current		_	$3.5~V \leq V_{IN} \leq 16~V, \\ I_{OUT} = 250~mA$	_	12	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	72	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz}, \ 3.5 \text{ V} \leq V_{IN} \leq 16 \text{ V}, \\ I_{OUT} = 50 \text{ mA} $	62	72	_	dB
Drangut voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V_D	_	I _{OUT} = 500 mA	_	0.35	0.65	V
Peak circuit current	I _{PEAK}	_	_	0.60	1.15	1.40	Α
Short circuit current	I _{SC}		_	0.60	1.15	1.40	Α

TA48M03F

Electrical Characteristics (unless otherwise specified, $V_{IN}=5$ V, $I_{OUT}=250$ mA, $T_i=25$ °C, $C_{IN}=0.1$ μF , $C_{OUT}=10$ μF)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	2.88	3.0	3.12	
Output voltage	Vout	_	$\begin{array}{l} 4~V \leq V_{IN} \leq 16~V, \\ 5~mA \leq I_{OUT} \leq 500~mA, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C \end{array}$	2.85	3.0	3.15	V
Line regulation	Reg·line	_	4 V ≤ V _{IN} ≤ 16 V	_	8	21	mV
Load regulation	Reg·load	_	$5 \text{ mA} \le I_{OUT} \le 500 \text{ mA}$	_	45	95	mV
Quiescent current	I _B	_	$ \label{eq:lower_state} \begin{array}{l} 4~V \leq V_{IN} \leq 16~V, \\ I_{OUT} = 0~mA \end{array} $	_	0.8	1.4	mA
Quiescent current		_	$\begin{array}{l} 4~V \leq V_{IN} \leq 16~V, \\ I_{OUT} = 250~mA \end{array}$	_	12	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	90	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz}, 4 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ I_{OUT} = 50 \text{ mA} $	60	70	_	dB
Dranaut voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V _D	_	I _{OUT} = 500 mA	_	0.35	0.65]
Peak circuit current	I _{PEAK}	_	_	0.60	1.20	1.45	Α
Short circuit current	I _{SC}		_	0.60	1.20	1.45	Α



TA48M033F

Electrical Characteristics (unless otherwise specified, $V_{IN}=5.3$ V, $I_{OUT}=250$ mA, $T_j=25$ °C, $C_{IN}=0.1$ μF , $C_{OUT}=10$ μF)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	3.168	3.3	3.432	
Output voltage	Vout	_	$\begin{array}{l} 4.3 \ V \leq V_{IN} \leq 16 \ V, \\ 5 \ mA \leq I_{OUT} \leq 500 \ mA, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C \end{array}$	3.135	3.3	3.465	٧
Line regulation	Reg·line	_	$4.3~V \leq V_{IN} \leq 16~V$	_	10	23	mV
Load regulation	Reg·load	_	$5 \text{ mA} \le I_{OUT} \le 500 \text{ mA}$	_	45	105	mV
	1-	_	$ 4.3 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ \text{I}_{OUT} = 0 \text{ mA} $	_	0.8	1.4	- mA
Quiescent current	IB	_	$\begin{array}{l} 4.3 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ \text{I}_{OUT} = 250 \text{ mA} \end{array}$	_	12	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	90	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz}, 4.3 \text{ V} \leq V_{IN} \leq 16 \text{ V}, \\ I_{OUT} = 50 \text{ mA} $	60	70	_	dB
Dranout voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V _D	_	I _{OUT} = 500 mA	_	0.35	0.65] V
Peak circuit current	I _{PEAK}	_	_	0.60	1.20	1.45	Α
Short circuit current	I _{SC}	_	_	0.60	1.20	1.45	Α

TA48M0345F

Electrical Characteristics

(unless otherwise specified, $V_{IN} = 5.45$ V, $I_{OUT} = 250$ mA, $T_i = 25^{\circ}$ C, $C_{IN} = 0.1$ μ F, $C_{OUT} = 10$ μ F)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	3.312	3.45	3.588	
Output voltage	Vout	_	$ \begin{array}{l} 4.45 \; V \leq V_{IN} \leq 16 \; V, \\ 5 \; mA \leq I_{OUT} \leq 500 \; mA, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C \end{array} $	3.278	3.45	3.622	V
Line regulation	Reg·line	_	$4.45 \text{ V} \le \text{V}_{IN} \le 16 \text{ V}$	_	12	25	mV
Load regulation	Reg·load	_	5 mA ≤ I _{OUT} ≤ 500 mA	_	45	110	mV
Quiescent current	I _B	_	$\begin{array}{l} 4.45 \ V \leq V_{IN} \leq 16 \ V, \\ I_{OUT} = 0 \ mA \end{array}$	_	0.8	1.4	mA.
Quescent current		_	$\begin{array}{l} 4.45 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V}, \\ \text{I}_{OUT} = 250 \text{ mA} \end{array}$	_	12	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	90	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz}, 4.45 \text{ V} \leq V_{IN} \leq 16 \text{ V}, \\ I_{OUT} = 50 \text{ mA} $	60	70	_	dB
Dranaut voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V_D	_	I _{OUT} = 500 mA	_	0.35	0.65]
Peak circuit current	I _{PEAK}	_	_	0.60	1.20	1.45	Α
Short circuit current	I _{SC}		_	0.60	1.20	1.45	Α



TA48M04F

Electrical Characteristics (unless otherwise specified, V_{IN} = 6 V, I_{OUT} = 250 mA, T_j = 25°C, C_{IN} = 0.1 μ F, C_{OUT} = 10 μ F)

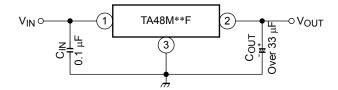
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	3.84	4.0	4.16	
Output voltage	Vout	_	$\begin{array}{l} 5~V \leq V_{IN} \leq 16~V, \\ 5~mA \leq I_{OUT} \leq 500~mA, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C \end{array}$	3.8	4.0	4.2	V
Line regulation	Reg·line	_	5 V ≤ V _{IN} ≤ 16 V	_	11	28	mV
Load regulation	Reg·load	_	$5 \text{ mA} \le I_{OUT} \le 500 \text{ mA}$	_	45	115	mV
	1-	_	$ 5 \text{ V} \leq \text{V}_{\text{IN}} \leq 16 \text{ V}, \\ \text{I}_{\text{OUT}} = 0 \text{ mA} $	_	0.9	1.4	mA.
Quiescent current	IB	_	$ 5 \text{ V} \leq \text{V}_{\text{IN}} \leq 16 \text{ V}, \\ \text{I}_{\text{OUT}} = 250 \text{ mA} $	_	13	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	110	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz, } 5 \text{ V} \leq \text{V}_{IN} \leq 16 \text{ V,} $ $I_{OUT} = 50 \text{ mA} $	58	68	_	dB
Dranout voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V _D	_	I _{OUT} = 500 mA	_	0.35	0.65	V
Peak circuit current	I _{PEAK}	_	_	0.60	1.25	1.50	Α
Short circuit current	I _{SC}	_	_	0.60	1.25	1.50	Α

TA48M05F

Electrical Characteristics (unless otherwise specified, V_{IN} = 7 V, I_{OUT} = 250 mA, T_i = 25°C, C_{IN} = 0.1 μ F, C_{OUT} = 10 μ F)

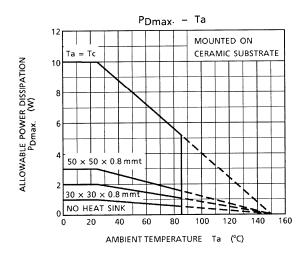
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
		_	_	4.8	5.0	5.2	
Output voltage	V _{OUT}	_	$ 6~V \leq V_{IN} \leq 18~V, \\ 5~mA \leq I_{OUT} \leq 500~mA, \\ 0^{\circ}C \leq T_{j} \leq 125^{\circ}C $	4.75	5.0	5.25	V
Line regulation	Reg·line	_	6 V ≤ V _{IN} ≤ 18 V	_	15	35	mV
Load regulation	Reg·load	_	$5 \text{ mA} \le I_{OUT} \le 500 \text{ mA}$	_	50	135	mV
Quiescent current	IB	_	$ 6 \text{ V} \leq \text{V}_{IN} \leq 18 \text{ V}, \\ \text{I}_{OUT} = 0 \text{ mA} $	_	1.0	1.4	- mA
Quescent current		_	$ 6 \text{ V} \leq \text{V}_{\text{IN}} \leq 18 \text{ V}, \\ \text{I}_{\text{OUT}} = 250 \text{ mA} $	_	13	25	IIIA
Output noise voltage	V _{NO}	_	$10 \text{ Hz} \le f \le 100 \text{ kHz},$ $I_{OUT} = 50 \text{ mA}$	_	125	_	μVrms
Ripple rejection	R.R.	_	$ f = 120 \text{ Hz, } 6 \text{ V} \leq \text{V}_{IN} \leq 18 \text{ V,} \\ I_{OUT} = 50 \text{ mA} $	58	68	_	dB
Dranaut voltage	\/-	_	I _{OUT} = 250 mA	_	0.17	0.35	V
Dropout voltage	V_D	_	I _{OUT} = 500 mA	_	0.35	0.65	V
Peak circuit current	I _{PEAK}		_	0.60	1.30	1.55	Α
Short circuit current	I _{SC}	_	_	0.60	1.30	1.55	Α

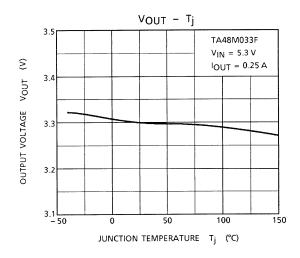
Standard Application Circuit

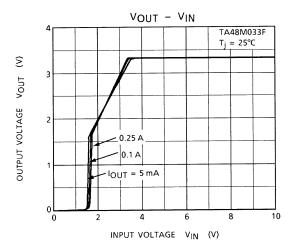


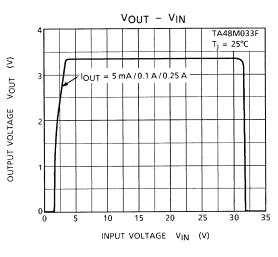
Be sure to connect a capacitor near the input terminal and output terminal between both terminals and GND. The capacitances should be determined experimentally. In particular, adequate investigation should be made so that there is no problem even in high or low temperatures.

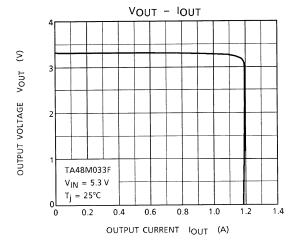
Note: Depending on the type of capacitor being used to connect to the output, characteristics (capacitance, frequency and others) may decline and the output may oscillate. To prevent this, Toshiba recommends a tantalum electrolytic capacitor that has a small fluctuation in capacitance characteristics.

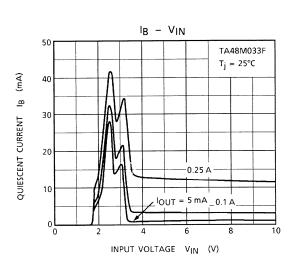


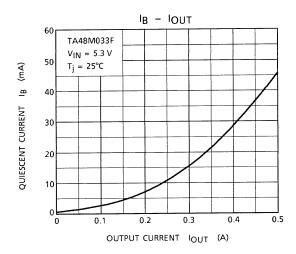


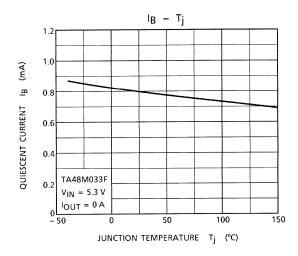


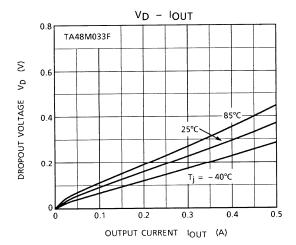


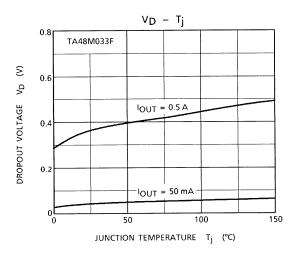


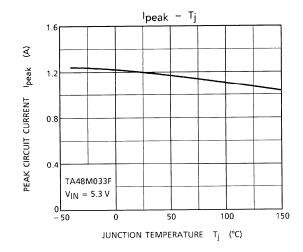


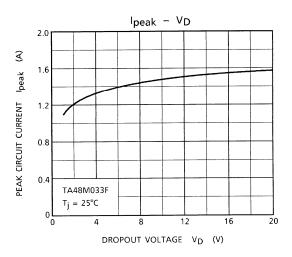


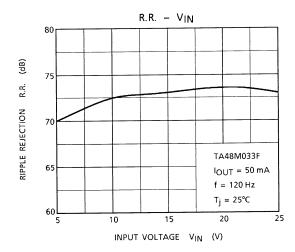


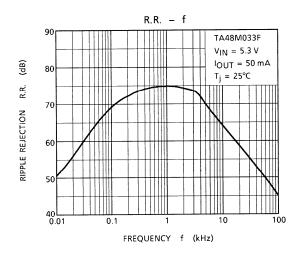


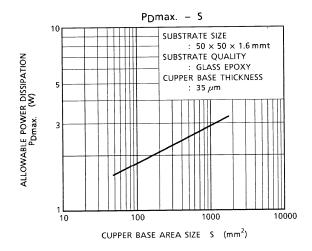






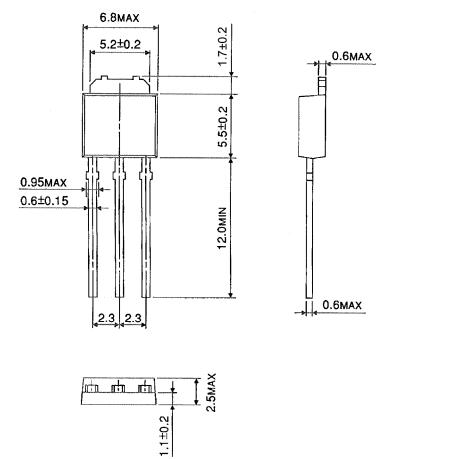






Package Dimensions

HSIP3-P-2.30B Unit: mm

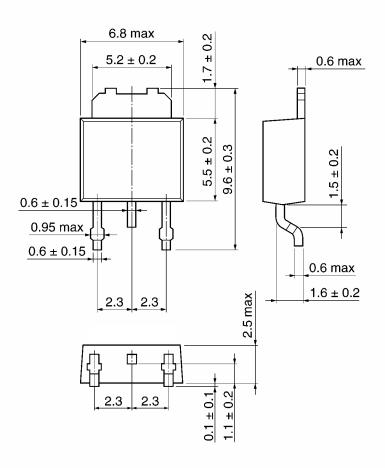


Weight: 0.36 g (typ.)

Package Dimensions

HSOP3-P-2.30A

Unit: mm



Weight: 0.36 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN

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